NSN 5961-01-306-9686

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-306-9686 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.170 inches **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2000.0 reverse voltage, peak **Voltage Tolerance In Percent:** -2.5/+2.5 **Current Rating Per Characteristic:** 500.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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